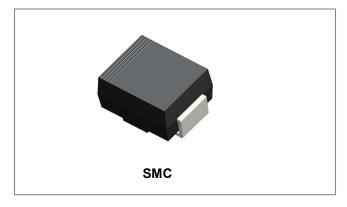






S3A THRU S3M SURFACE MOUNT GENERAL RECTIFIER Reverse Voltage - 50 to 1000 Volts Forward Current - 3.0 Amperes



Features

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Low reverse leakage
- Built-in strain relief, ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 260° C/10 seconds at terminals
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: SMC molded plastic
- Lead: Solder Plated, Solderable Per MIL-STD 750, Method 2026
- Polarity: Color band denotes cathode end
- Weight: 0.21 grams

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic	Symbol	S3A	S3B	S3D	S3G	S3J	S3K	S3M	Units
Maximum repetitive peak reverse voltage Maximum DC blocking voltage	$V_{RRM} \ V_{DC}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	\ \
Maximum average forward rectified current @T _L = 110°C	I _(AV)	3.0				Α			
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	100.0			А				
Maximum instantaneous forward voltage at 3.0A	V _F	1.1			V				
Maximum DC reverse current @T _A = 25°C at rated DC blocking voltage @T _A = 100°C	I _R	5.0 100.0			μA				
Typical Junction Capacitance (Note 1)	Сл	C _J 60.0			pF				
Typical Thermal Resistance (Note 2)	R _{θJA}	50.0			°C/W				
Operating and Storage Temperature Range T _{J.} T _{ST}		-65 to +175					°C		

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas.

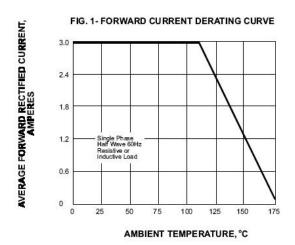
- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •

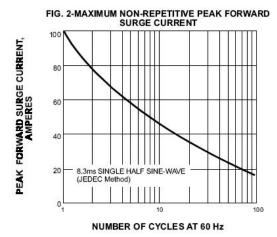


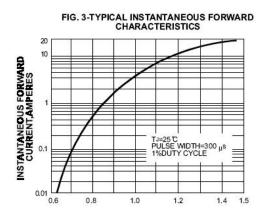




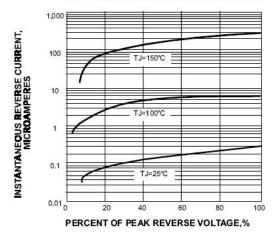
Ratings and Characteristics Curves











INSTANTANEOUS FORWARD VOLEAGE,

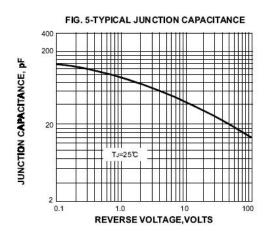
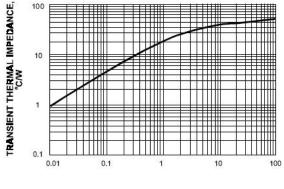




FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



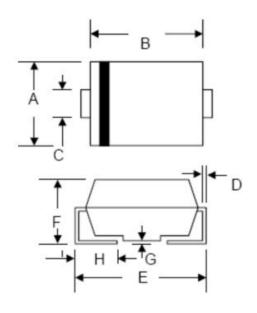
- t,PULSE DURATION,sec.
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Mechanical Dimensions SMC



SYMBOL	Millir	meters	Inches		
STIVIBUL	Min.	Max.	Min.	Max.	
А	5.59	6.22	0.220	0.245	
В	6.60	7.11	0.260	0.280	
С	2.90	3.20	0.114	0.126	
D	0.152	0.305	0.006	0.012	
Е	7.75	8.13	0.305	0.320	
F	2.00	2.62	0.079	0.103	
G	-	0.203	-	0.008	
Н	0.76	1.52	0.030	0.060	

Ordering Information

Device	Package	Shipping		
S3A-S3M	SMC (Pb-Free)	3000pcs / reel		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 S3A
 = Part Name

 YY
 = Year

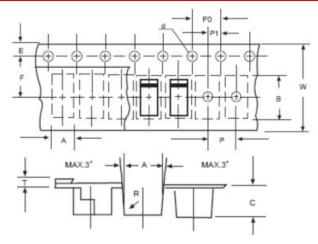
 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Carrier Tape Specification SMC



SYMBOL	Millimeters			
STWIBUL	Min.	Max.		
Α	5.90	6.10		
В	8.20	8.40		
O	2.40	2.60		
d	1.40	1.60		
E	1.40	1.60		
F	7.60	7.70		
Р	7.90	8.10		
P0	3.90	4.10		
P1	3.90	4.10		
T	-	0.600		
W	15.80	16.20		

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